

# Radar Pulsed Power Transistor 220W, 1.2-1.4 GHz, 150µs Pulse, 10% Duty

M/A-COM Products Released, 30 May 07

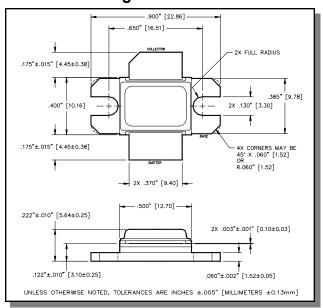
#### **Features**

- NPN silicon microwave power transistors
- · Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	70	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ic	21	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	700	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



### Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 100mA		BV <sub>CES</sub>	70	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	10	mA
Thermal Resistance	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.25	°C/W
Output Power	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	220	=	W
Power Gain	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	7.4	=	dB
Collector Efficiency	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	ης	50	-	%
Input Return Loss	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	RL	-	-9	dB
Pulse Droop	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	Droop	-	0.8	dB
Load Mismatch Tolerance	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 40V, Pin = 40W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

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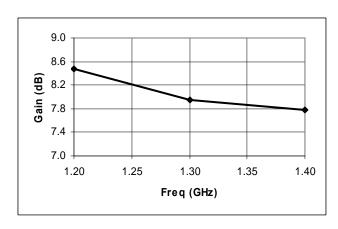


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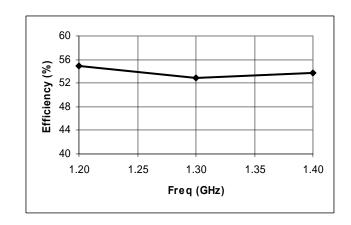
### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	Droop (dB)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	40	281	8.47	12.8	54.8	0.34	-16.7	S	Р
1.3	40	250	7.95	11.8	53.0	0.22	-16.8	S	Р
1.4	40	240	7.78	11.2	53.7	0.24	-15.4	S	Р

### Gain vs. Frequency

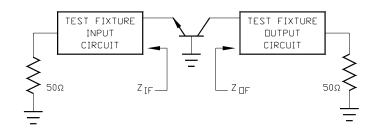


#### Collector Efficiency vs. Frequency



#### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)		
1.2	3.3 - j2.7	2.0 - j1.5		
1.3	3.4 - j2.1	1.9 - j1.6		
1.4	3.6 - j1.3	1.7 - j1.4		



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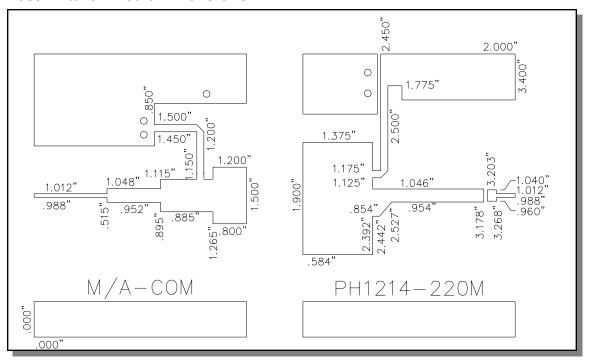
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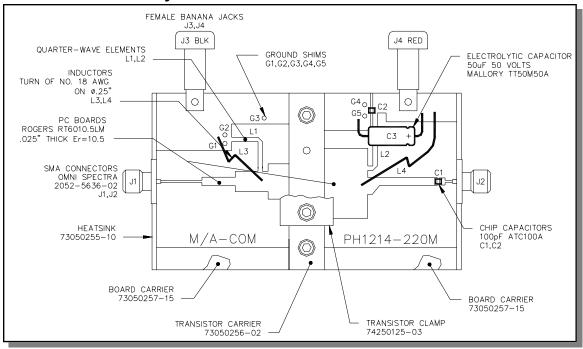
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#### **Test Fixture Circuit Dimensions**



# **Test Fixture Assembly**



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